

DMTH8030LPDW

80V 175°C DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max Tc = +25°C	
80V	26mΩ @ V _{GS} = 10V	28.5A	
80.0	45mΩ @ V _{GS} = 4.5V	21A	

Description and Applications

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

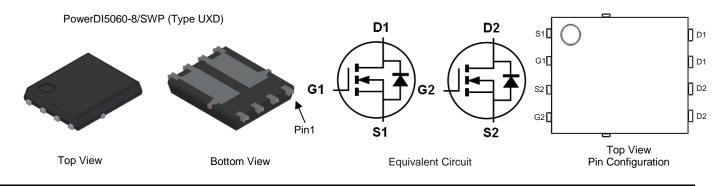
- DC-DC converters
- Motors

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Additional Tin-Plated on Sidewall Pads for Optical Solder Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMTH8030LPDWQ)

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMTH8030LPDW-13	PowerDI5060-8/SWP (Type UXD)	2500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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Marking Information



);; = Manufacturer's Marking H8030LPDW = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 22 = 2022) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	Vdss	80	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current, V _{GS} = 10V (Note 6) $T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$		ID	28.5 20	А
Maximum Body Diode Forward Current	ls	29	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	113.5	А	
Pulsed Body Diode Forward Current (10µs Pulse, Tc = +25°C, Package	lsм	113.5	А	
Avalanche Current, L = 0.3mH	las	12.5	А	
Avalanche Energy, L = 0.3mH	Eas	23.4	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Thermal Resistance, Junction to Ambient (Note 5)		Reja	48	°C/W
Total Power Dissipation	T _A = +25°C	PD	3.1	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	3.7	°C/W
Total Power Dissipation	$T_C = +25^{\circ}C$	PD	41	W
Operating and Storage Temperature Range	•	TJ, TSTG	-55 to +175	°C

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Thermal resistance from junction to solder point (on the exposed drain pin).



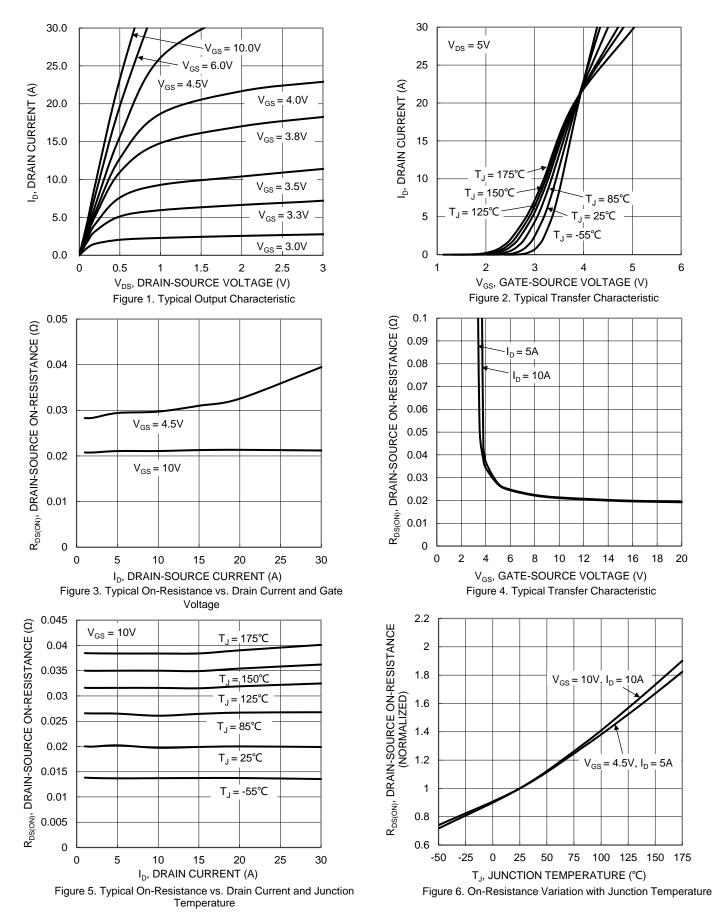
Electrical Characteristics (@T_C = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Symbol	IAIIII	тур	WIGA	Onit	Test condition	
Drain-Source Breakdown Voltage	BV _{DSS}	80	_		V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current				1	μA	$V_{\text{GS}} = 64V, V_{\text{GS}} = 0V$	
Gate-Source Leakage				±100	nA	$V_{DS} = 64V, V_{GS} = 0V$ $V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)	I _{GSS}			100	ПА	$VGS = \pm 20V, VDS = 0V$	
Gate Threshold Voltage	Vgs(th)	1.3	_	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
	VGS(TH)		20	2.5	v	$V_{GS} = 10V, I_D = 10A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		20	45	mΩ	$V_{GS} = 4.5V, I_D = 5A$	
Diode Forward Voltage	1/05		0.9	4.5	V	,	
DYNAMIC CHARACTERISTICS (Note 8)	Vsd		0.9	1.2	v	Vgs = 0V, Is = 10A	
Input Capacitance	Ciss	_	631	1	1		
						$V_{DS} = 40V, V_{GS} = 0V,$ f = 1.0MHz	
Output Capacitance	Coss		200		pF		
Reverse Transfer Capacitance	Crss	_	19.5	—			
Gate Resistance	Rg	_	1.1	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge ($V_{GS} = 4.5V$)	Qg	_	5.4	—			
Total Gate Charge (V _{GS} = 10V)	Qg		10.4	—	nC	Vps = 40V. lp = 7.5A	
Gate-Source Charge	Qgs	_	1.8	—	ne	VDS = 40V, ID = 7.5A	
Gate-Drain Charge	Q _{gd}	_	2.4	—			
Turn-On Delay Time	t _{D(ON)}		7.1	_		V _{DD} = 40V, V _{GS} = 4.5V, R _G = 2.7Ω, I _D = 10A	
Turn-On Rise Time	tR		9.7	_	1		
Turn-Off Delay Time	tD(OFF)		18.6	_	ns		
Turn-Off Fall Time	tF		8.6	—	1		
Body Diode Reverse Recovery Time	t _{RR}	_	28.5	—	ns	I _F = 7.5A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Qrr	_	21.7	_	nC	IF = 7.5A, di/dt = 100A/µs	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



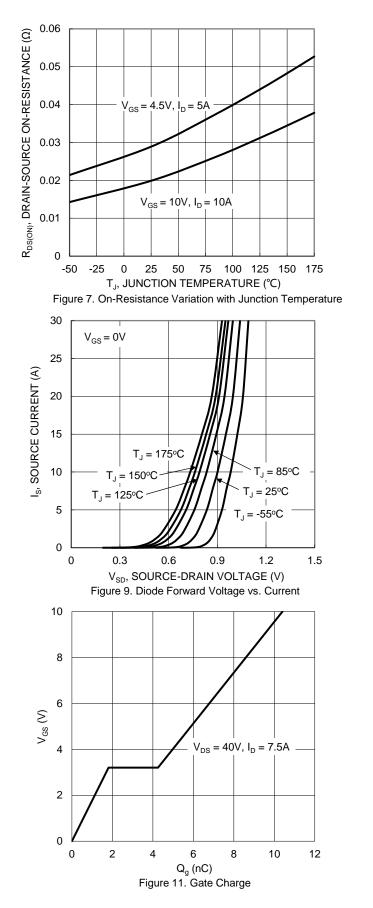
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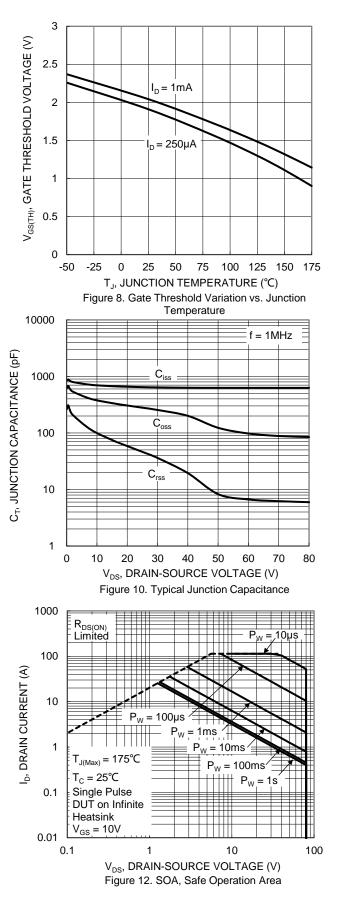


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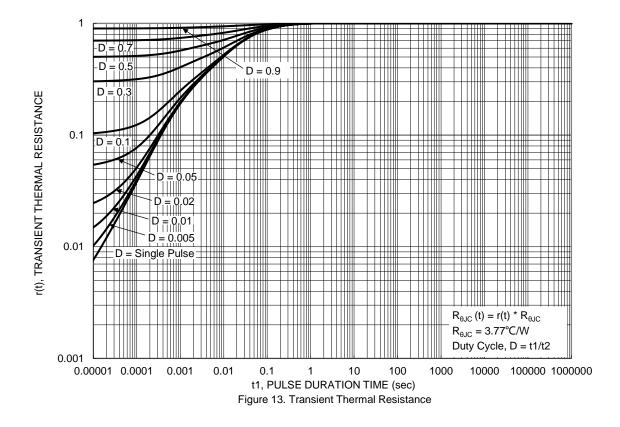


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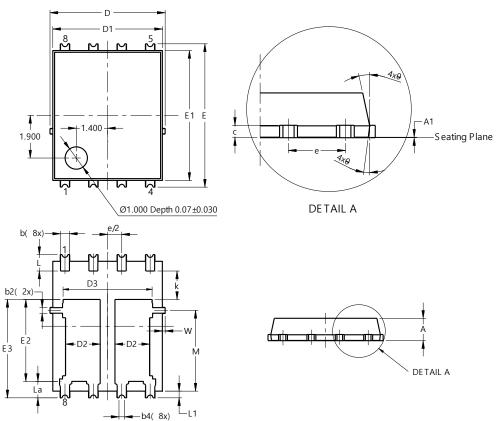






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

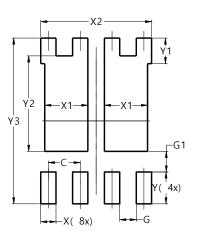


PowerDI5060-8/SWP (Type UXD)

Po	PowerDI5060-8/SWP (Type UXD)					
Dim	Min Max		Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05				
b	0.30	0.50	0.41			
b2	0.20	0.35	0.25			
b4	().25REF	-			
С	0.230	0.330	0.277			
D	5.15 BSC					
D1	4.70	5.10	4.90			
D2	1.46 1.66		1.55			
D3	3.78	4.18	3.98			
E	6	6.40 BS0	0			
E1	5.60	6.00	5.80			
E2	3.46	3.86	3.66			
E2a	4.195	4.595	4.395			
е	1	1.27BSC)			
k	1.05					
L	0.635	0.835	0.735			
La	0.635	0.835	0.735			
L1	0.200	0.400	0.300			
М	3.205	4.005	3.605			
W	0.025	0.225	0.125			
θ	10°	12°	11°			
θ1	6°	8°	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8/SWP (Type UXD)

Dimensions	Value		
Dimensions	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	1.720		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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